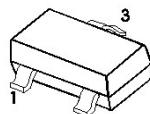


**SOT-23**



1. BASE
2. Emitter
3. COLLECTOR

Marking: 1K

**特征 Features**

- Power Dissipation of 200mW
- Ideally suited for automatic insertion
- For switching and AF amplifier applications
- AEC-Q 101 qualified

**机械数据 Mechanical Data**

- Small Outline Plastic Package
- Epoxy UL: 94V-0
- Mounting Position: Any

极限值和温度特性(TA = 25°C 除非另有规定)

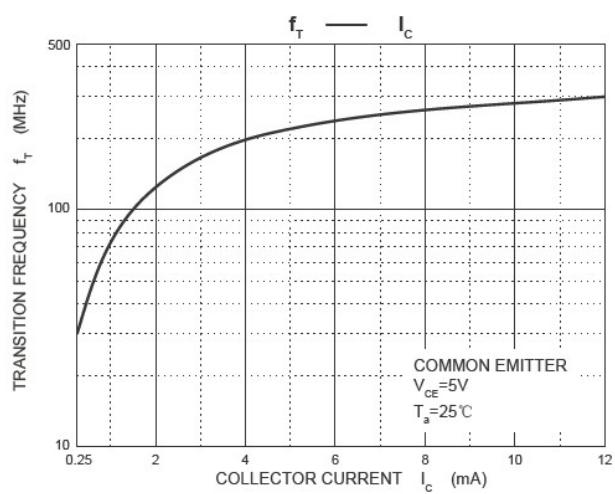
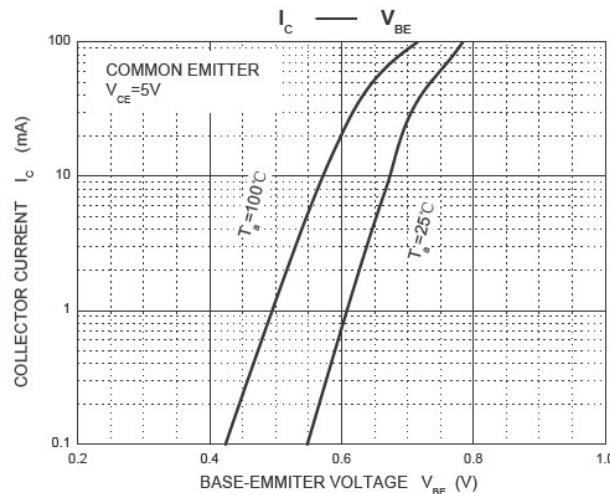
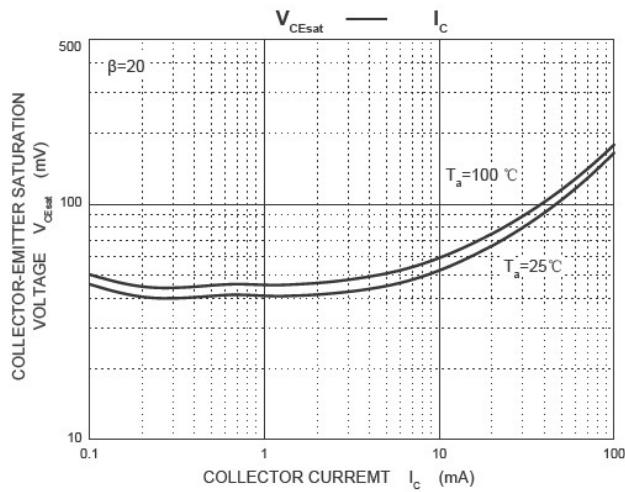
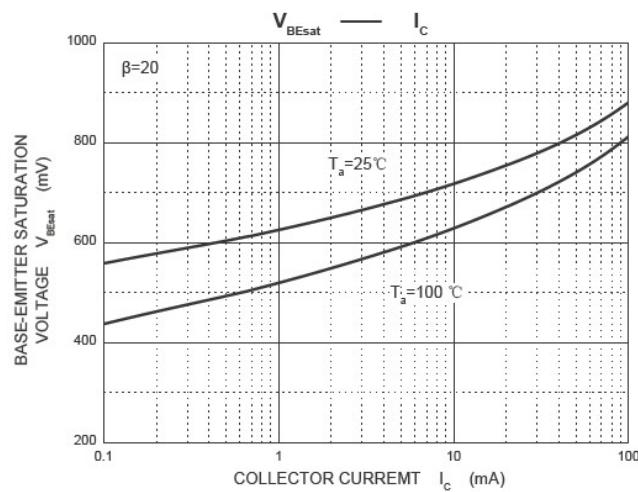
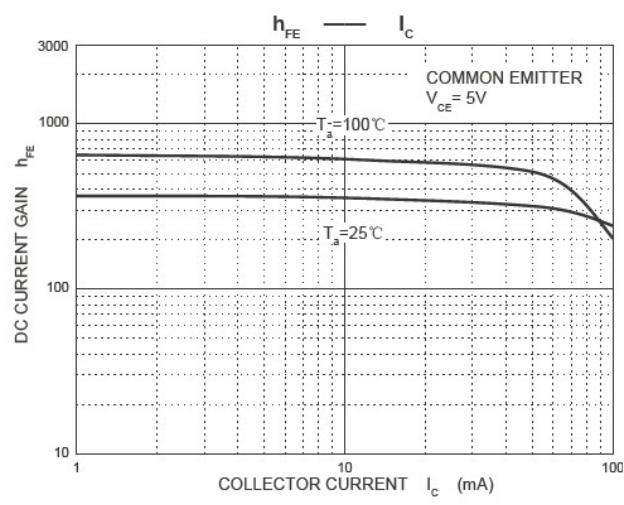
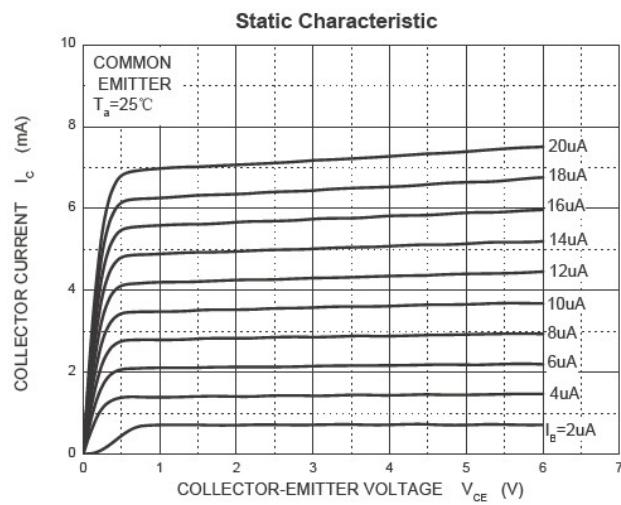
**Maximum Ratings & Thermal Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified.)

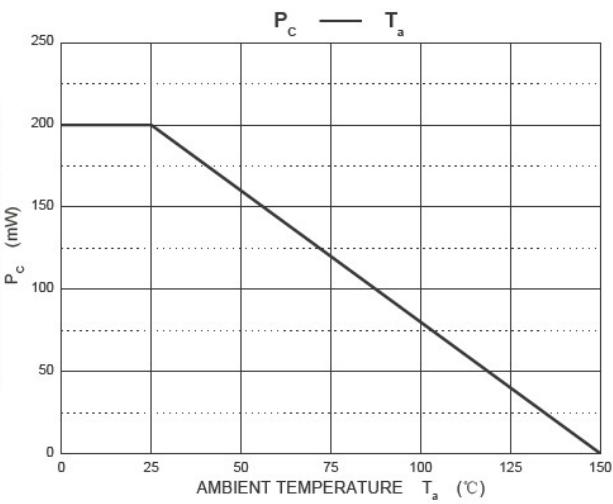
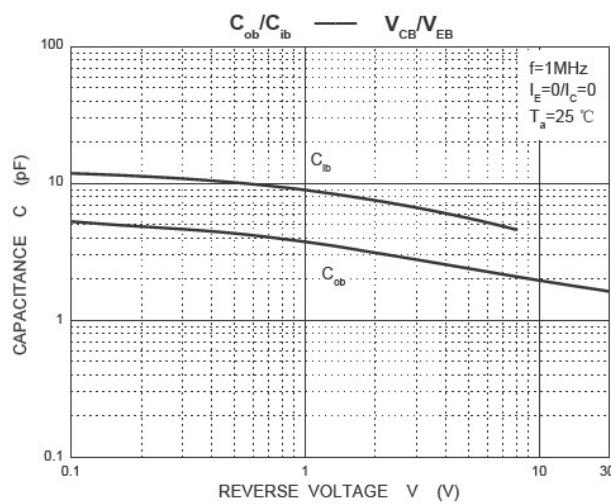
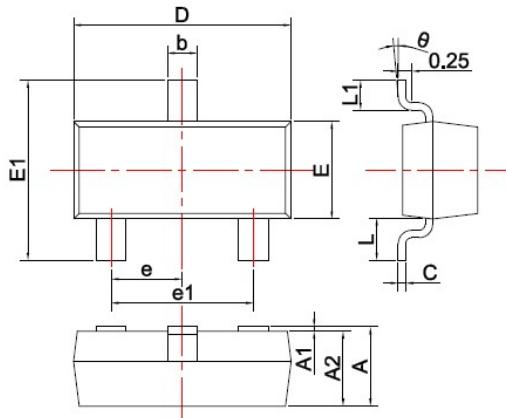
参数 Parameters	符号 Symbol	数值 Value	单位 Unit
Collector-Base Voltage	V <sub>CBO</sub>	30	V
Collector-Emitter Voltage	V <sub>CEO</sub>	30	V
Emitter -Base Voltage	V <sub>EBO</sub>	6	V
Collector Current-Continuous	I <sub>c</sub>	100	mA
Collector Power Dissipation	P <sub>c</sub>	200	mW
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55~+150	°C
Thermal resistance From junction to ambient	R <sub>θJA</sub>	625	°C/W

电特性 (TA = 25°C 除非另有规定)

**Electrical Characteristics** (Ratings at 25°C ambient temperature unless otherwise specified).

参数 Parameter	符号 Symbols	测试条件 Test Condition	界限 Limits		单位 Unit
			Min	Max	
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>c</sub> =10uA, I <sub>e</sub> =0	30		V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>c</sub> =10mA, I <sub>b</sub> =0	30		V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>e</sub> =10uA, I <sub>c</sub> =0	6		V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =30V, I <sub>e</sub> =0		100	nA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =30V, I <sub>b</sub> =0		100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>c</sub> =0		100	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>c</sub> =2mA	200	450	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>c</sub> =100mA, I <sub>b</sub> =5mA		0.50	V
Base -emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>c</sub> =100mA, I <sub>b</sub> =5mA		1.10	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>c</sub> =10mA, f=100MHz	100		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		4.5	pF

**Typical characteristics**


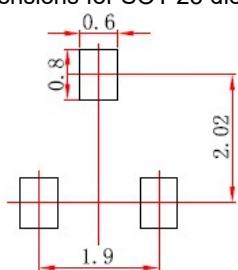

**SOT-23 PACKAGE OUTLINE** Plastic surface mounted package


SYMBOL	DIMENSIONS	
	MIN	MAX
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
$\theta$	0°	8°

Unit: mm

**焊盘设计参考** Precautions: PCB Design

Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



## Note:

1. Controlling dimension: In millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

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